

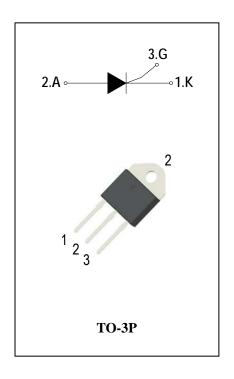
SCRs

General Description

The 55A SCR series of silicon controlled rectifiers, with high ability to withstand the shock loading of large current, provide high dv/dt rate with strong resistance to electromagnetic interference. They are especially recommended for use on solid state relay, motorcycle, power charger, T-tools etc.

Features

- ◆ Repetitive Peak Off-State Voltage: 1000V and 1200V
- ◆ R.M.S On-State Current (IT(RMS)=55 A)
- ♦ These are Pb-Free Devices



Absolute Maximum Ratings

Symbol	Items	Conditions		Ratings	Unit				
V_{DRM}	Repetitive Peak Off-State Voltage	Ti=25°C	ADS55A100H	1000	V				
V_{RRM}	Repetitive peak reverse voltage	Tj=25°C	ADS55A120H	1200	V				
I _{T(AV)}	Average On-State Current	Half Sine Wave , Tc = 80°C		40	Α				
I _{T(RMS)}	R.M.S On-State Current	Half Sine Wave , Tc = 80°C		55	Α				
I _{TSM}	Surge On-State Current	1/2 Cycle, Sine Wave Non-Repetitive, tp=10ms(50Hz)Tj =25°C		520	Α				
l ² t	I ² t for Fusing	Tj =25°C,tp =10ms		1350	A ² S				
Р _{GМ}	Forward Peak Gate Power Dissipation	Tj =125°C, Pulse Width ≤ 20μs		10	W				
$P_{G(AV)}$	Forward Average Gate Power Dissipation	Tj =25°C, tp =10ms		1	W				
I _{GM}	Peak Gate Current	Tj =125°C, Pulse Width ≤ 20μs		5	Α				
Tj	Operating Junction Temperature			- 40 ~ 125	°C				
T _{STG}	Storage Temperature							- 40 ~ 150	°C





Electrical Characteristics (Tj = 25°C unless otherwise specified)

Symbol	Items	Conditions		ADS55A100H/120H			Unit
				S	Blank	W	
		$V_{DRM} = V_{RRM}$			10		uA
I _{DRM}	Peak Forward Reverse	Tj = 25°C	Max.				
I _{RRM}	Blocking Current	V _{DRM} = V _{RRM} Tj = 125°C	Wax.	6		mA	
V _{TM}	Peak On-State Voltage	I_{TM} = 80A, t_p = 380 μ s	Max.	1.6		V	
V_{GD}	Non-Trigger Gate Voltage	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $Tj = 125^{\circ}\text{C}$	Min.	0.2		V	
V_{GT}	Gate Trigger Voltage	Max. 1.5		1.5		V	
I _{GT}	Gate Trigger Current	$V_D = 12V$, $R_L = 33\Omega$	Max.	15	30	80	mA
I _H	Holding Current	I _T = 0.5A	Max.	30	40	150	mA
ΙL	Latching Current	I _G = 1.2 I _{GT}	Max.	50	60	200	mA
dV/dt	Critical Rate of Rise of Off-State Voltage	$V_D = 2/3V_{DRM}$ gate open $Tj = 125^{\circ}C$	Min.	700	1000	1500	V/µs
R _{th(j-c)}	Junction to case (AC)		Max.	0.65		°C/W	
R _{th(j-a)}	Junction to ambient		Max.	55		°C/W	

2 / 6 www.advsemi.com Feb,2013 -Rev.3.01

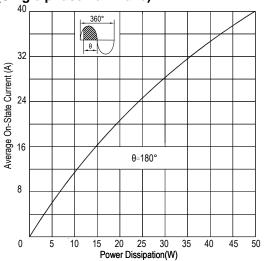
FIG.2: Average on-state current VS Allowable

case Temperature(Single phase half wave)

120

90

FIG.1: Maximum average power dissipation (Single phase half wave)



Gate trigger current VS Junction temperature

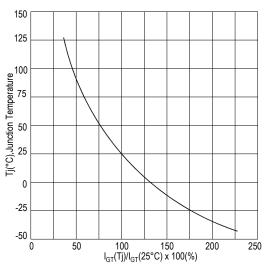
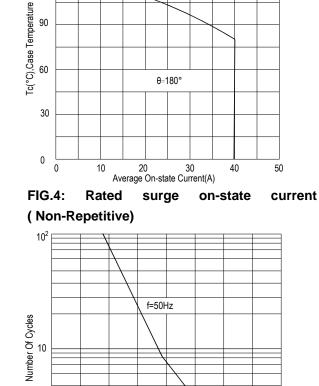


FIG.5: On-state characteristics(Max)



Tj=25°C Max

320

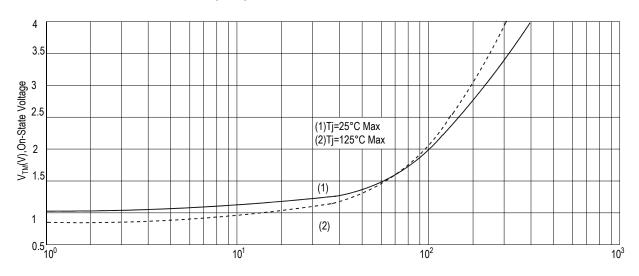
Surge On-State Current(A)

160 240

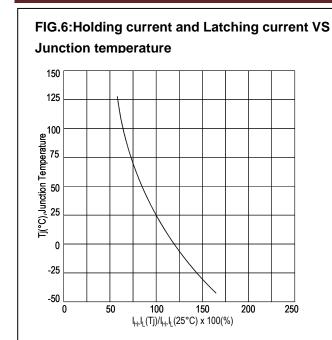
400

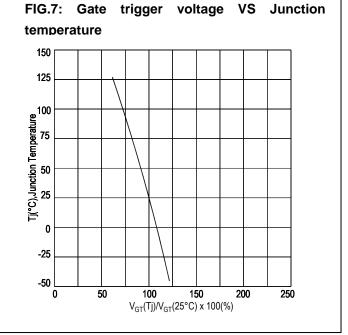
480

640



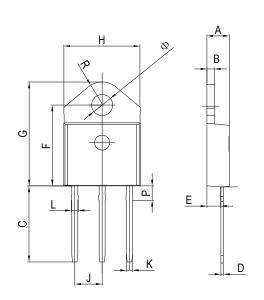






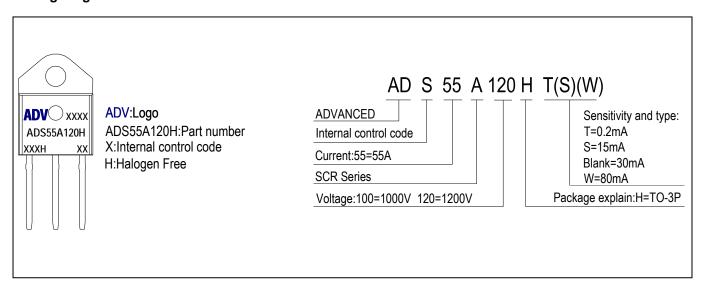
4 / 6 www.advsemi.com Feb,2013 -Rev.3.01

PACKAGE MECHANICAL DATA TO-3P Package Dimension



	Dimensions In		Dimensions In		
Symbol	Millimeters		Inches		
	Min	Max	Min	Max	
Α	4.4	4.6	0.173	0.181	
В	1.45	1.55	0.057	0.061	
С	14.35	15.60	0.565	0.614	
D	0.5	0.7	0.020	0.028	
E	2.7	2.9	0.106	0.114	
F	15.8	16.5	0.622	0.650	
G	20.4	21.1	0.815	0.831	
Н	15.1	15.5	0.594	0.610	
J	5.4	5.65	0.213	0.222	
K	1.2	1.4	0.047	0.055	
Ø	4.08	4.20	0.161	0.165	
L	1.35	1.50	0.053	0.059	
Р	2.8	3.0	0.110	0.118	
R	4.60 typ.		0.181 typ.		

Making Diagram



Ordering information

Part number	Package	Marking	Packing	Quantity			
ADS55A100H#	TO-3P	ADS55A100H#	Tube	30pcs			
ADS55A120H#	TO-3P	ADS55A120H#	Tube	30pcs			
Note:# = Gate Trigger Current Sensitivity and type							



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6 / 6 www.advsemi.com Feb,2013 -Rev.3.01